

## Dual N-Channel 2.5-V (G-S) MOSFET, ESD Protected

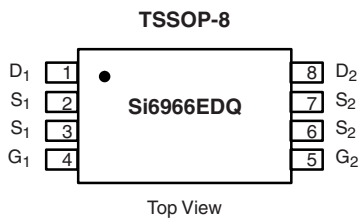
PRODUCT SUMMARY		
$V_{DS}$ (V)	$R_{DS(on)}$ ( $\Omega$ )	$I_D$ (A)
20	0.030 at $V_{GS} = 4.5$ V	$\pm 5.2$
	0.040 at $V_{GS} = 2.5$ V	$\pm 4.5$

### FEATURES

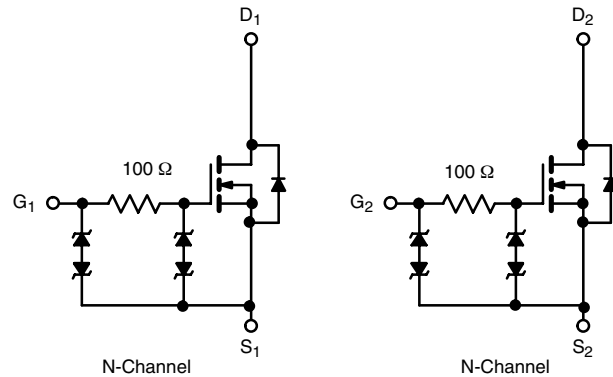
- Halogen-free
- ESD Protected: 4000 V



**RoHS**  
COMPLIANT



Ordering Information: Si6966EDG-T1-GE3 (Lead (Pb)-free and Halogen-free)



ABSOLUTE MAXIMUM RATINGS $T_A = 25$ °C, unless otherwise noted			
Parameter	Symbol	Limit	Unit
Drain-Source Voltage	$V_{DS}$	20	V
Gate-Source Voltage	$V_{GS}$	$\pm 12$	
Continuous Drain Current ( $T_J = 150$ °C) <sup>a, b</sup>	$I_D$	$T_A = 25$ °C	$\pm 5.2$
		$T_A = 70$ °C	$\pm 4.0$
Pulsed Drain Current	$I_{DM}$	$\pm 30$	A
Continuous Source Current (Diode Conduction) <sup>a, b</sup>	$I_S$	1.25	
Maximum Power Dissipation <sup>a, b</sup>	$P_D$	$T_A = 25$ °C	1.25
		$T_A = 70$ °C	0.72
Operating Junction and Storage Temperature Range	$T_J, T_{stg}$	- 55 to 150	°C

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Typical	Maximum	Unit	
Maximum Junction-to-Ambient <sup>a</sup>	$R_{thJA}$	$t \leq 10$ s	110	°C/W	
		Steady State	115		

Notes:

a. Surface Mounted on FR4 board.

b.  $t \leq 10$  s.

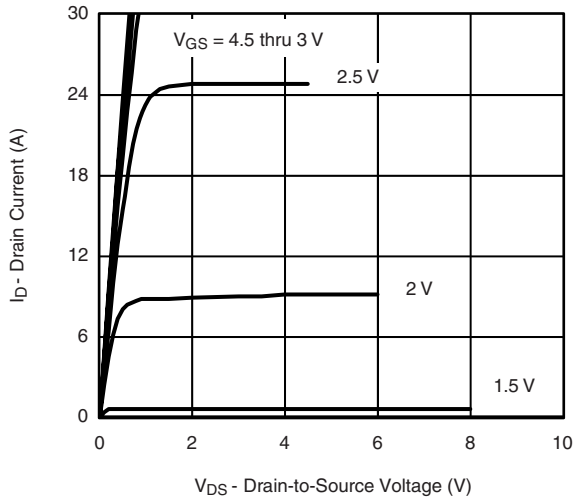
<b>SPECIFICATIONS</b> $T_J = 25\text{ }^\circ\text{C}$ , unless otherwise noted						
Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
<b>Static</b>						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$ , $I_D = 250\text{ }\mu\text{A}$	0.6			V
Gate-Body Leakage	$I_{GSS}$	$V_{DS} = 0\text{ V}$ , $V_{GS} = \pm 4.5\text{ V}$			$\pm 100$	nA
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = +20\text{ V}$ , $V_{GS} = 0\text{ V}$			1	$\mu\text{A}$
		$V_{DS} = 20\text{ V}$ , $V_{GS} = 0\text{ V}$ , $T_J = 55\text{ }^\circ\text{C}$			25	
On-State Drain Current <sup>a</sup>	$I_{D(on)}$	$V_{DS} \geq 5\text{ V}$ , $V_{GS} = 4.5\text{ V}$	30			A
Drain-Source On-State Resistance <sup>a</sup>	$R_{DS(on)}$	$V_{GS} = 4.5\text{ V}$ , $I_D = 5.2\text{ A}$		0.021	0.030	$\Omega$
		$V_{GS} = 2.5\text{ V}$ , $I_D = 4.5\text{ A}$		0.028	0.040	
Forward Transconductance <sup>a</sup>	$g_{fs}$	$V_{DS} = 10\text{ V}$ , $I_D = 5.2\text{ A}$		20		S
Diode Forward Voltage <sup>a</sup>	$V_{SD}$	$I_S = 1.25\text{ A}$ , $V_{GS} = 0\text{ V}$		0.65	1.2	V
<b>Dynamic<sup>b</sup></b>						
Total Gate Charge	$Q_g$	$V_{DS} = 15\text{ V}$ , $V_{GS} = 4.5\text{ V}$ , $I_D = 5.2\text{ A}$		15	25	nC
Gate-Source Charge	$Q_{gs}$			2.5		
Gate-Drain Charge	$Q_{gd}$			4.5		
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = 10\text{ V}$ , $R_L = 10\text{ }\Omega$ $I_D \cong 1\text{ A}$ , $V_{GEN} = 4.5\text{ V}$ , $R_G = 6\text{ }\Omega$		100	200	ns
Rise Time	$t_r$			130	250	
Turn-Off Delay Time	$t_{d(off)}$			420	800	
Fall Time	$t_f$			220	450	
Source-Drain Reverse Recovery Time	$t_{rr}$	$I_F = 1.25\text{ A}$ , $di/dt = 100\text{ A}/\mu\text{s}$		210	500	

## Notes:

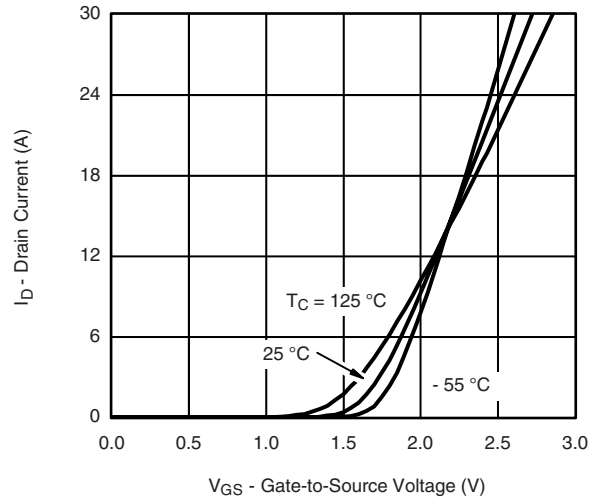
- a. Pulse test; pulse width  $\leq 300\text{ }\mu\text{s}$ , duty cycle  $\leq 2\%$ .  
b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

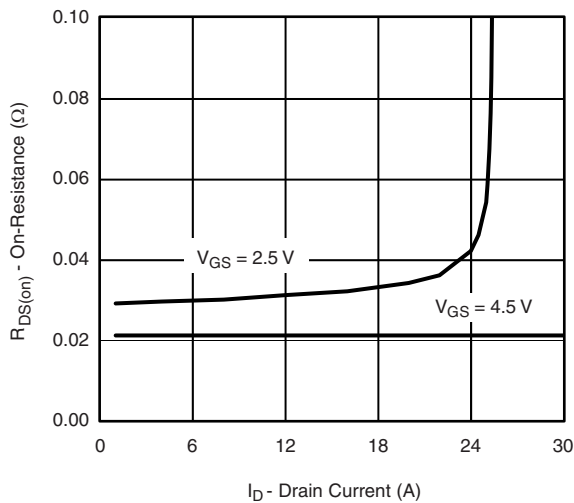
**TYPICAL CHARACTERISTICS** 25 °C, unless otherwise noted



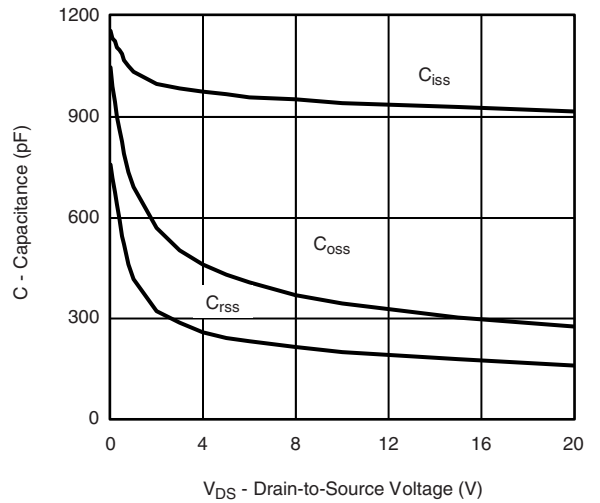
**Output Characteristics**



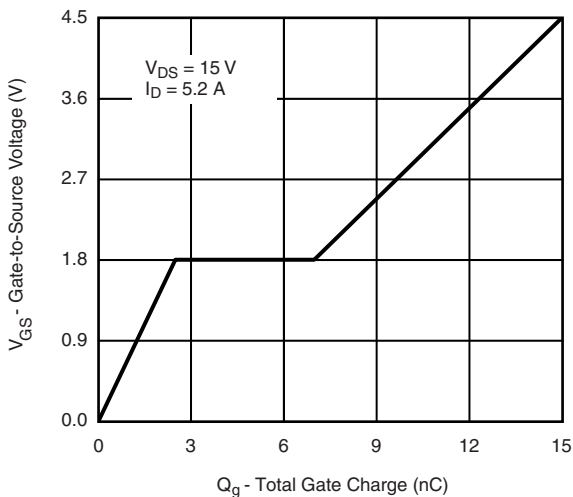
**Transfer Characteristics**



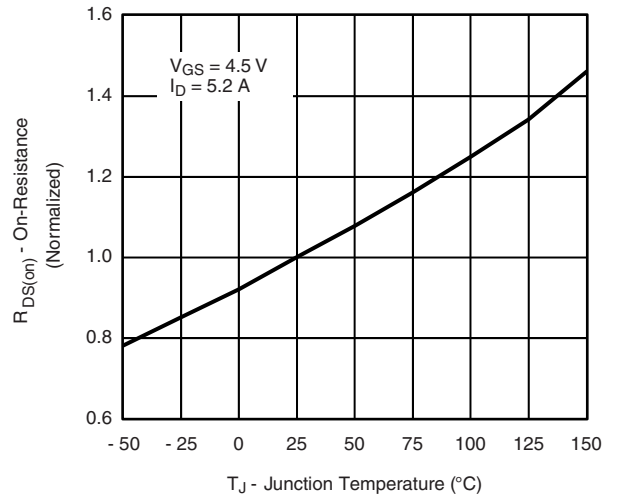
**On-Resistance vs. Drain Current**



**Capacitance**

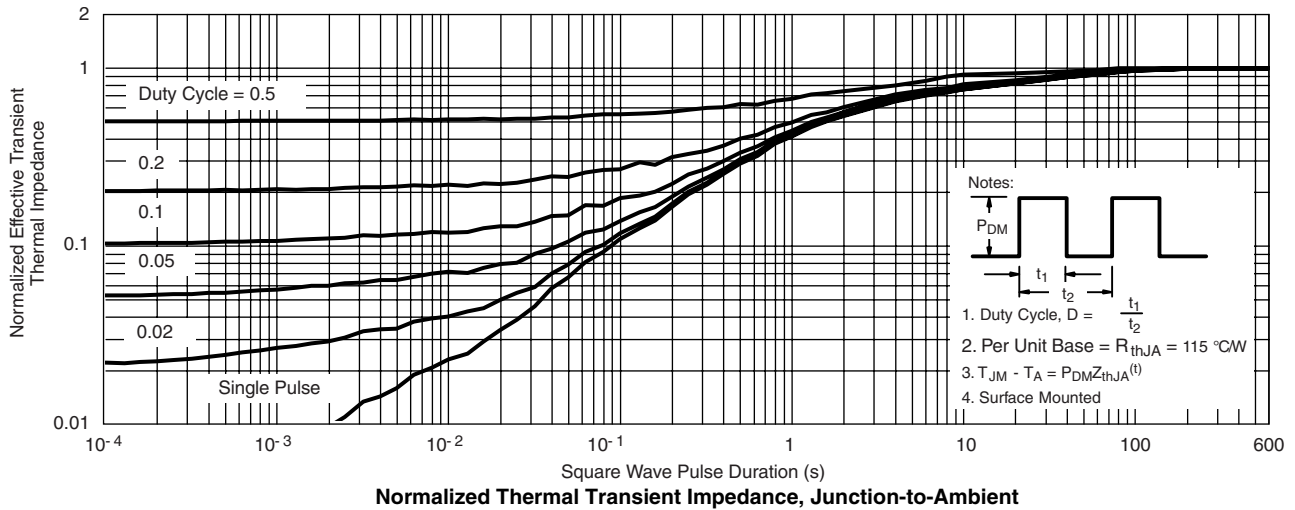
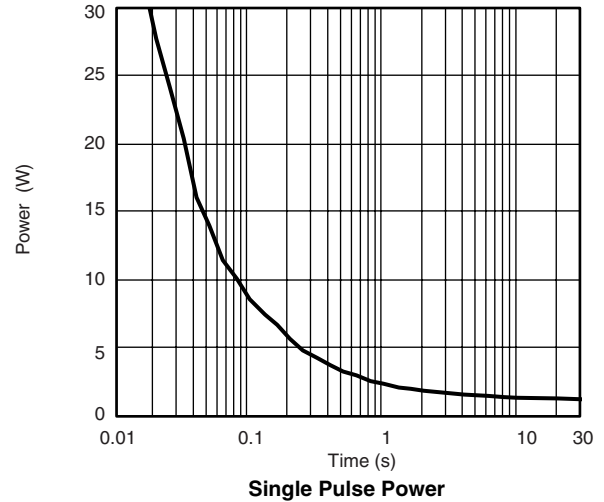
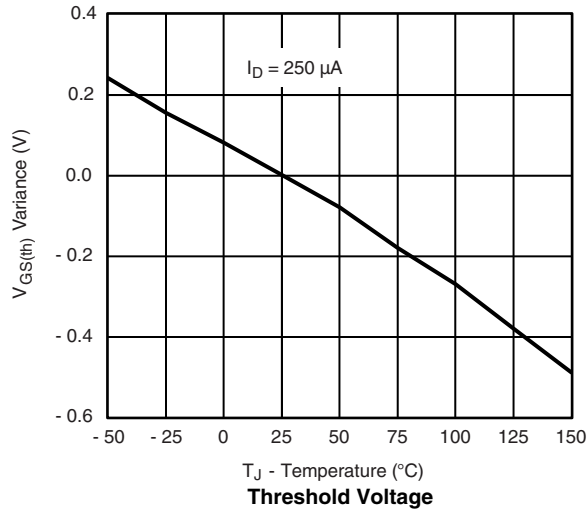
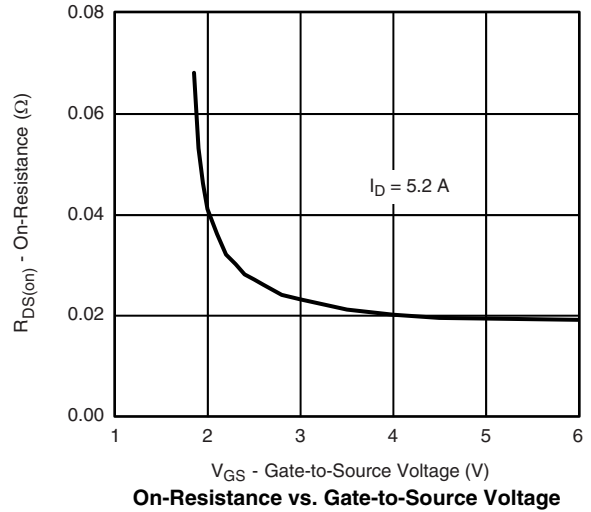
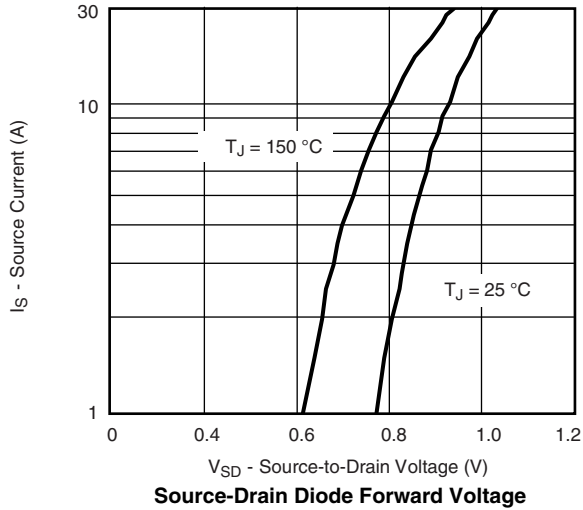


**Gate Charge**



**On-Resistance vs. Junction Temperature**

**TYPICAL CHARACTERISTICS** 25 °C, unless otherwise noted



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